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LM25141-Q1 2.2-MHz, 42-V Synchronous Buck Controller With Low I^Q

1 Features

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- AEC-Q100 Qualified for Automotive Applications:
	- Device Temperature Grade 1: –40°C to +125°C Ambient Operating Temperature
	- Device HBM ESD Classification Level 2
	- Device CDM ESD Classification Level C4B
- V_{IN} 3.8 V to 42 V (47 V Absolute Maximum)
- Output: Fixed 3.3 V, 5 V, or Adjustable From 1.5 V to 15 V With ±0.8% Accuracy
- Optional Frequency Shift by Varying an Analog Voltage or RT Resistor
- Meets CISPR 25 / EN 55025 EMI Standards
	- Fixed 2.2-MHz or 440-kHz Switching Frequency With ±5% Accuracy
	- High-Side and Low-Side Gate Drive With Slew Rate Control
	- Optional Spread Spectrum
- Optional Synchronization to an External Clock
- Shutdown Mode I_Q : 10 µA Typical
- Low Standby Mode I_O : 35 µA Typical
- 75-mV Current Limit Threshold With ±0.9% **Accuracy**
- External Resistor or DCR Current Sensing
- Output Enable Logic Input
- Hiccup Mode for Sustained Overload
- Power-Good Indication Output
- Selectable Diode Emulation or Forced PWM
- VQFN-24 Package With Wettable Flanks
- • Create a Custom Design Using the LM25141-Q1 With the [WEBENCH](https://webench.ti.com/wb5/WBTablet/PartDesigner/quickview.jsp?base_pn=LM25141-Q1&origin=ODS&litsection=features)[®] Power Designer

2 Applications

- Automotive Applications Including:
	- Infotainment Systems
	- Instrumentation Clusters
	- Advanced Driver Assistance Systems (ADAS)

3 Description

The LM25141-Q1 is a synchronous buck controller, intended for high-voltage, wide- V_{IN} , step-down regulator applications. The control method is peak current-mode control. Current-mode control provides inherent line feed-forward, cycle-by-cycle current limiting, and ease of loop compensation. The LM25141-Q1 features slew rate control to simplify the compliance with CISPR and automotive EMI requirements.

The LM25141-Q1 has two selectable switching frequencies: 2.2 MHz and 440 kHz. Gate drivers with slew rate control can be adjusted to reduce EMI.

In light or no-load conditions, the LM25141-Q1 operates in skip cycle mode for improved low power efficiency. The LM25141-Q1 has a high-voltage bias regulator with automatic switch-over to an external bias to reduce the I_{Ω} current from V_{IN} . Additional features include frequency synchronization, cycle-bycycle current limit, hiccup-mode fault protection for sustained overload, and power-good output.

Device Information[\(1\)](#page-0-0)

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Simplified Schematic

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Table of Contents

4 Revision History

5 Pin Configuration and Functions

RGE Package

Connect Exposed Pad on bottom to AGND and PGND on the PCB.

Pin Functions

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Pin Functions (continued)

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6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) High junction temperatures degrade operating lifetimes. Operating lifetime is de-rated for junction temperatures greater than 125°C.

6.2 ESD Ratings

(1) AEC Q100-002 indicates that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

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6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

(1) *Recommended Operating Conditions* are conditions under which the device is intended to be functional. For specifications and test conditions, see *Electrical [Characteristics](#page-5-2)*.

(2) High junction temperatures degrade operating lifetimes. Operating lifetime is de-rated for junction temperatures greater than 125°C.

6.4 Thermal Information

(1) For more information about traditional and new thermal metrics, see the *[Semiconductor](http://www.ti.com/lit/pdf/spra953) and IC Package Thermal Metrics* application report.

6.5 Electrical Characteristics

 $T_J = -40^{\circ}$ C to +125°C; typical values $T_J = 25^{\circ}$ C, VIN = 12 V, VCCX = 5 V, VOUT = 5 V, EN = 5 V, OSC = VDD, $F_{SW} = 2.2$ MHz, no-load on the drive outputs (HO, HOL, LO, and LOL outputs), over operating free-air temperature range (unless otherwise noted) $(1)(2)$

(1) All minimum and maximum limits are specified by correlating the electrical characteristics to process and temperature variations and applying statistical process control.

(2) The junction temperature (T_J in °C) is calculated from the ambient temperature (T_A in °C) and power dissipation (P_D in Watts) as follows: T^J = T^A + (P^D × RθJA) where RθJA (in °C/W) is the package thermal impedance provided in the *Thermal [Information](#page-5-1)* section.

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Electrical Characteristics (continued)

 $T_J = -40^{\circ}$ C to +125°C; typical values $T_J = 25^{\circ}$ C, VIN = 12 V, VCCX = 5 V, VOUT = 5 V, EN = 5 V, OSC = VDD, $F_{SW} = 2.2$ MHz, no-load on the drive outputs (HO, HOL, LO, and LOL outputs), over operating free-air temperature range (unless otherwise noted)^{[\(1\)\(2\)](#page-8-1)}

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Electrical Characteristics (continued)

 $T_J = -40^{\circ}$ C to +125°C; typical values $T_J = 25^{\circ}$ C, VIN = 12 V, VCCX = 5 V, VOUT = 5 V, EN = 5 V, OSC = VDD, $F_{SW} = 2.2$ MHz, no-load on the drive outputs (HO, HOL, LO, and LOL outputs), over operating free-air temperature range (unless otherwise noted)^{[\(1\)\(2\)](#page-8-1)}

Electrical Characteristics (continued)

 $T_J = -40^{\circ}$ C to +125°C; typical values $T_J = 25^{\circ}$ C, VIN = 12 V, VCCX = 5 V, VOUT = 5 V, EN = 5 V, OSC = VDD, $F_{SW} = 2.2$ MHz, no-load on the drive outputs (HO, HOL, LO, and LOL outputs), over operating free-air temperature range (unless otherwise noted) $(1)(2)$

6.6 Switching Characteristics

over operating free-air temperature range (unless otherwise noted)

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6.7 Typical Characteristics

At $T_A = 25$ °C, unless otherwise noted

Typical Characteristics (continued)

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Typical Characteristics (continued)

At $T_A = 25^{\circ}C$, unless otherwise noted

7 Detailed Description

7.1 Overview

The LM25141-Q1 is a switching controller which features all of the functions necessary to implement a high efficiency buck power supply that can operate over a wide input voltage range. The LM25141-Q1 is configured to provide a single fixed 3.3-V, or 5-V output, or an adjustable output between 1.5 V to 15 V. This easy to use controller integrates high-side and low-side MOSFET drivers capable of sourcing 3.25 A and sinking 4.25 A peak. The control method is current mode control which provides inherent line feed-forward, cycle-by-cycle current limiting, and ease of loop compensation. With the OSC pin connected to VDD, the default oscillator frequency is 2.2 MHz. With the OSC pin grounded, the oscillator frequency is 440 kHz. The LM25141-Q1 can be synchronized by applying an external clock to the DEMB pin. Fault protection features include current limiting, thermal shutdown, and remote shutdown capability.

The LM25141-Q1 incorporates features that simplify compliance with the CISPR and automotive EMI requirements. The LM25141-Q1 has optional spread spectrum to reduce the peak EMI and gate drivers with slew rate control. The VQFN-24 package features an exposed pad to aid in thermal dissipation.

7.2 Functional Block Diagram

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7.3 Feature Description

7.3.1 High Voltage Start-Up Regulator

The LM25141-Q1 contains an internal high voltage VCC bias regulator that provides the bias supply for the PWM controller and the gate drivers for the external MOSFETs. The input pin (VIN) can be connected directly to an input voltage source up to 42 V. The output of the VCC regulator is set to 5 V. When the input voltage is below the VCC set-point level, the VCC output tracks VIN with a small voltage drop. In high voltage applications, take extra care to ensure the VIN pin does not exceed the absolute maximum voltage rating of 47 V including line or load transients. Voltage ringing on the VIN pin that exceeds the absolute maximum ratings can damage the IC. Use a high quality bypass capacitor between VIN and ground to minimize ringing.

7.3.2 VCC Regulator

The VCC regulator output current limit is 75 mA (minimum). At power-up, the regulator sources current into the capacitors connected to the VCC pin. When the voltage on the VCC pin exceeds 3.4 V, the output is enabled and the soft-start sequence begins. The output remains active unless the voltage on the VCC pin falls below the VCC_(UVLO) threshold of 3.2 V (typical) or the enable pin is switched to a low state. The recommended range for the VCC capacitor is 2.2 µF to 4.7 µF

An internal 5-V linear regulator generates the VDDA bias supply. Bypass VDDA with a 100-nF or greater ceramic capacitor to ensure a low noise internal bias rail. Normally VDDA is 5 V, but there are two operating conditions where it regulates at 3.3 V. The first is in skip cycle mode with VOUT of 3.3 V. The second is when V_{IN} is less than 5 V. Under these conditions, both VCC and VDD drop below 5 V. Internal power dissipation in the VCC Regulator can be minimized by connecting the VCCX pin to a 5 V output or to an external 5-V supply. If VCCX > 4.5 V, VCCX is internally connected to VCC and the internal VCC regulator is disabled. If VCCX is unused, it should be grounded. Never connect the VCCX pin to a voltage greater than 6.5 V.

7.3.3 Oscillator

The LM25141-Q1 has an internal trimmed oscillator with two frequency options: 2.2 MHz, or 440 kHz. With the OSC pin connected to VDDA the oscillator frequency is 2.2 MHz. With the OSC pin grounded, the oscillator frequency is 440 kHz. The state of the OSC pin is read and latched during VCC power-up and cannot be changed until VCC drops below the $VCC_{(UVLO)}$ threshold.

The oscillator frequency can be modulated up or down from the nominal oscillator frequency (2.2 MHz or 440 kHz) on demand by connecting a resistor from the RT pin to ground (refer to [Figure](#page-14-0) 19). To disable the frequency modulation option, the RT pin can be grounded or left open. If the RT pin is connected to ground during power-up the frequency modulation option is latch-off and cannot be changed unless VCC is allowed to drop below the VCC_(UVLO) threshold. If the RT pin is left open during power-up the frequency modulation option will be disabled, but it can be enabled at a later time by switching in a valid RT resistor. When the frequency modulation option is disabled, the LM25141-Q1 operates at the internal oscillator frequency (2.2 MHz or 440 kHz).

On power up, after soft start is complete and the output voltage is in regulation, a 16-µs timer is initiated. If a valid RT resistor is connected, the LM25141-Q1 switches to the frequency set by the RT resistor n the completion of the 16-µs time delay.

The modulation range for 2.2 MHz is 1.8 MHz to 2.53 MHz (refer to [Table](#page-14-1) 1). If an RT resistor value > 95 k Ω (typical) is placed on the RT pin, the LM25141-Q1 controller assumes that the RT pin is open and will use the internal oscillator. If an RT resistor < 27 kΩ (typical) is connected, the controller uses the internal oscillator. To calculate an RT resistor for a specific oscillator frequency, use [Equation](#page-13-1) 1 for the 2.2-MHz frequency range or [Equation](#page-14-2) 2 for the 440-kHz frequency range.

RT_{2.2 MHz} =
$$
\frac{\frac{1}{F_{sw}} - 0.0216}{0.0086}
$$

where

 RT is kΩ and F_{SW} is in MHz (1)

Feature Description (continued)

$$
RT_{440 \text{ kHz}} = \frac{\frac{1}{Fsw} \cdot 1.38 \times 10^{-5}}{4.5 \times 10^{-5}}
$$

where

• RT is in kΩ and F_{SW} is in kHz (2)

Table 1. RT Resistance vs Oscillator Frequency

S1	S ₂	RT RESISTANCE (TYPICAL) 2.2 MHz	2.2-MHZ OSCILLATOR RANGE (TYPICAL)	RT RESISTANCE (TYPICAL) 440 kHz	440-kHz OSCILLATOR RANGE (TYPICAL)
X		$> 95 k\Omega$	Internal Oscillator	$> 95 k\Omega$	Internal Oscillator
OFF	OFF	61.98 k	1.8 MHz	73.8 kQ Total	300 kHz
OFF	ON	50.18 k Ω Total	2.2 MHz	50.1 kQTotal	440 kHz
OΝ	OFF	43.2 k Ω	2.53 MHz	44.2 k Ω	500 kHz
v		$<$ 27 k Ω	Internal Oscillator	$<$ 27 k Ω	Internal Oscillator

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Figure 19. RT Connection Circuit, 2.2 MHz

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Figure 20. RT Connection Circuit, 440 kHz

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An alternative method to modulate the oscillator frequency is to use an analog voltage connected to the RT pin through a resistor. See [Figure](#page-15-0) 21. An analog voltage of 0.0 V to 0.6 V modulates the oscillator frequency between 1.8 MHz to 2.53 MHz (OSC at 2.2 MHz), or 300 kHz to 500 kHz (OSC at 440 kHz). The analog voltage source must be able to sink current.

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Figure 21. Analog Voltage Control of the Oscillator Frequency

When the LM25141-Q1 is in the low I_0 standby mode, the controller will set the RT pin to a high impedance state and ignore the RT resistor. After coming out of standby mode, the controller will monitor the RT pin. If a valid resistor is connected, and there have been 16 µs of continuous switching without a zero-crossing event, the LM25141-Q1 switches to the frequency set by the RT resistor.

7.3.4 Synchronization

To synchronize the LM25141-Q1 to an external source, apply a logic level clock signal to the DEMB pin. The synchronization range is 350 kHz to 550 kHz when the internal oscillator is set to 440 kHz. When the internal oscillator is set to 2.2 MHz, the synchronization range is 1.8 MHz to 2.6 MHz. If there is a valid RT resistor and a synchronization signal, the LM25141-Q1 with ignore the RT resistor and synchronize the controller to the external clock. Under low V_{IN} conditions, when the minimum off-time is reached (100 ns), the synchronization clock is ignored to allow the frequency to drop to maintain output voltage regulation.

7.3.5 Frequency Dithering (Spread Spectrum)

The LM25141-Q1 provides a frequency dithering option that is enabled by connecting a capacitor from the DITH pin to AGND. A triangular waveform centered at 1.2 V is generated across the C_{DITH} capacitor. Refer to [Figure](#page-16-0) 22. The triangular waveform modulates the oscillator frequency by \pm 5% of the nominal frequency set by the OSC pin or by an RT resistor. The C_{DITH} capacitance value sets the rate of the low frequency modulation. A lower C_{DITH} capacitance will modulate the oscillator frequency at a faster rate than a higher capacitance. For the dithering circuit to effectively reduce the peak EMI, the modulation rate must be less than the oscillator frequency (Fsw). [Equation](#page-15-1) 3 calculates the DITH pin capacitance required to set the modulation frequency, FMOD.

$$
C_{\text{DTH}} = \frac{20 \, \mu\text{A}}{2 \times F_{\text{MOD}} \times 0.12 \,\text{V}} \tag{3}
$$

If the DITH pin is connected to VDDA during power-up the Dither feature is latch-off and cannot be changed unless VCC is allowed to drop below the VCC $_{(UVLO)}$ threshold. If the DITH pin is connected to ground on power up, Dither is disabled, but it can be enabled by raising the DITH pin voltage above ground and connecting it to C_{DTH} . When the LM25141 is synchronized to an external clock, Dither is disabled.

Figure 22. Dither Operation

7.3.6 Enable

The LM25141-Q1 has an enable input EN for start-up and shutdown control of the output. The EN pin can be connected to a voltage as high as 47 V. If the enable input is greater than 2.0 V the output is enabled. If the enable pin is pulled below 0.8 V, the output is in shutdown, and the LM25141-Q1 is switched to a low I_0 shutdown mode, with a 10-µA typical current drawn from the VIN pin. TI does not recommend leaving the EN pin left floating.

7.3.7 Power Good

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Figure 22. Dither Operation

1414-01 has an enable input EN for start-up and shutdown control

to a voltage as high as 47 V. If the enable input is greater than is

incorp The LM25141-Q1 includes an output voltage monitoring function to simplify sequencing and supervision. The power good function can be used to enable circuits that are supplied by the output voltage rail or to turnon sequenced supplies. The PG pin switches to a high impedance state when the output voltage is in regulation. The PG signal switches low when the output voltage drops below the lower power good threshold (92% typical) or rises above the upper power good threshold (110% typical). A 25-μs deglitch filter prevents any false tripping of the power good signal due to transients. TI recommends a pullup resistor of 10 kΩ from the PG pin to the relevant logic rail. Power good is asserted low during soft start and when the buck converter is disabled by EN.

7.3.8 Output Voltage

The LM25141-Q1 output can be configured for one of the two fixed output voltages with no external feedback resistors, or the output can be adjusted to the desired voltage using an external resistor divider. V_{OUT} can be configured as a 3.3-V output by connecting the FB pin to VDDA, or a 5-V output by connecting the FB pin to ground with a maximum resistance of 500 Ω. The FB connections (either VDDA or GND) are detected during power up.

The configuration setting is latched and cannot be changed until the LM25141-Q1 is powered down with VCC falling below VCC $_{(UVLO)}$ (3.4 V typical) and then powered up again.

Alternatively the output voltage can be set using an external resistive dividers from the output to the FB pin. The output voltage adjustment range is between 1.5 V and 15 V. The regulation threshold at the FB pin is 1.2 V (V_{REF}). To calculate R_{FB1} and R_{FB2} use [Equation](#page-16-1) 4. Refer to [Figure](#page-17-0) 23:

$$
R_{FB2} = \left(\frac{V_{OUT}}{V_{REF}} - 1\right) \times R_{FB1}
$$
\n(4)

The recommend starting point is to select R_{FB1} between 10 kΩ to 20 kΩ.

The Thevenin equivalent impedance of the resistive divider connected to the FB pin must be greater than 5 kΩ for the LM25141-Q1 to detect the divider and set the controller to the adjustable output mode. Refer to [Equation](#page-16-2) 5.

$$
R_{TH} = \frac{R_{FB1} \times R_{FB2}}{R_{FB1} + R_{FB2}} > 5k\Omega
$$

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If a low I_Q mode is required, take care when selecting the external resistors. The extra current drawn from the external divider is added to the LM25141-Q1 $I_{STANDBY}$ current (35 μ A typical). The divider current reflected to VIN is divided down by the ratio of V_{OUT}/V_{IN}. For example, if V_{IN} is 12V and V_{OUT} is set to 5.5 V with R_{FB1} 10 kΩ, and R_{FB2} = 35.7 kΩ, the input current at VIN required to supply the current in the feedback resistors is:

$$
I_{DIVIDER} = \frac{V_{OUT}}{R_{FB1} + R_{FB2}} \times \frac{V_{OUT}}{V_{IN}} = \frac{5.5 \text{ V}}{10 \text{ k} + 35.7 \text{ k}} \times \frac{5.5 \text{ V}}{12 \text{ V}} = 55.16 \text{ }\mu\text{A}
$$

where

$$
\bullet \quad V_{\text{IN}} = 12 \text{ V} \tag{6}
$$

The total input current in this condition is:

 $I_{VIN} \approx I_{STANDBY} + I_{DIVIDER} \approx 35 \mu A + 55.16 \mu \approx 90.16 \mu A$

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Figure 23. Voltage Feedback

7.3.8.1 Minimum Output Voltage Adjustment

There are two limitations to the minimum output voltage adjustment range: the LM25141-Q1 voltage reference of 1.2 V and the minimum switch node pulse width, t_{SW} .

The minimum controllable on-time at the switch node (t_{SW}) limits the voltage conversion ratio (V_{OUT}/V_{IN}). For fixed-frequency PWM operation, the voltage conversion ratio should meet the condition in [Equation](#page-17-1) 8:

$$
\frac{V_{\text{OUT}}}{V_{\text{IN}}} > t_{\text{sw}} \times F_{\text{SW}}
$$

where

- t_{SW} is 70 ns (typical)
- Fsw is the switching frequency (8)

 $\frac{1}{V_{IN}} > t_{sw}$ x

here

• t_{sw} is

• Fsw i

desired volt

hey operatic

ample, if the

sion ratio te
 $\frac{3V}{V} > 70$ ns x If the desired voltage conversion ratio does not meet the above condition, the controller transitions from fixed frequency operation into a pulse skipping mode to maintain regulation of the output voltage.

For example, if the desired output voltage is 3.3 V with a V_{IN} of 20 V and operating at 2.2 MHz, the voltage conversion ratio test is satisfied:

$$
\frac{3.3\,\text{V}}{20\,\text{V}} > 70\,\text{ns} \times 2.2\,\text{MHz}
$$
\n
$$
0.165 > 0.154 \tag{9}
$$

For wide V_{IN} applications and lower output voltages, an alternative is to use the LM25141-Q1 with a 440-kHz oscillator frequency. Operating at 440 kHz, the limitation of the minimum t_{SW} time is less significant. For example, if a 1.8-V output is required with a V_{IN} of 42 V:

 $\frac{1.8 \text{ V}}{42 \text{ V}}$ > 70ns × 440kHz > 70 ns \times $0.04286 > 0.0308$

(7)

7.3.9 Current Sense

There are two methods to sense the inductor current of the buck converter. The first is using current sense resistor in series with the inductor and the second is to use the DC resistance of the inductor (DCR sensing). [Figure](#page-18-0) 24 illustrates inductor current sensing using a current sense resistor. This configuration continuously monitors the inductor current providing accurate current-limit protection. For the best current-sense accuracy and over current protection, use a low inductance ±1% tolerance current-sense resistor between the inductor and output, with a Kelvin connection to the LM25141-Q1 sense amplifier.

If the peak differential current signal sensed from CS to VOUT exceeds 75 mV, the current limit comparator immediately terminates the HO output for cycle-by-cycle current limiting.

$$
R_{\text{SENSE}} = \frac{V_{(CS)}}{\left(I_{\text{OUT}(MAX)} + \frac{\Delta I}{2}\right)}
$$

where

$$
\bullet \quad V_{(CS)} = 75 \text{ mV} \tag{11}
$$

I_{OUT(MAX)} is the overcurrent set-point which is set higher than the maximum load current to avoid tripping the overcurrent comparator during load transients. ΔI is the peak-peak inductor ripple current.

Figure 24. Current Sense

7.3.10 DCR Current Sensing

For high-power applications which do not require high accuracy current-limit protection, DCR sensing may be preferable. This technique provides lossless and continuous monitoring of the output current using an RC sense network in parallel with the inductor. Using an inductor with a low DCR tolerance, the user can achieve a typical current limit accuracy within the range of $\pm 10\%$ to $\pm 15\%$ at room temperature.

Components R_{CS} and C_{CS} in [Figure](#page-19-0) 25 create a low-pass filter across the inductor to enable differential sensing of the voltage drop across inductor DCR. When $R_{CS} \times C_{CS}$ is equal to L_{OUT}/R_{DCR} , the voltage developed across the sense capacitor, C_{CS} , is a replica of the inductor DCR voltage waveform. Choose the capacitance of C_{CS} to be greater than 0.1 μF to maintain a low impedance sensing network, thus reducing the susceptibility of noise pickup from the switch node. Carefully observe the PCB layout guidelines to ensure the noise and DC errors do not corrupt the differential current-sense signals applied across the CS and VOUT pins.

The voltage drop across C_{CS} :

$$
V_{CS}(s) = \frac{1 + \frac{sL_{OUT}}{R_{DCR}}}{1 + sR_{CS}C_{CS}} Ipk \times R_{DCR}
$$

(12)

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Figure 25. DCR Current Sensing

 $R_{CS}C_{CS} = L_{OUT}/R_{DCR} \rightarrow$ accurate DC and AC current sensing

If the RC time constant is not equal to the $L_{\text{OUT}}/L_{\text{DRC}}$ time constant there is an error

 $R_{CS}C_{CS}$ > L_{OUT}/ R_{DCR} \rightarrow DC level still correct, the AC amplitude is attenuated

 $R_{CS}C_{CS}$ < L_{OUT}/ R_{DCR} \rightarrow DC level still correct, the AC amplitude is amplified

7.3.11 Error Amplifier and PWM Comparator

Eigure 25. DCR Current Sensing

DCR \rightarrow accurate DC and AC current sensing

Stant is not equal to the L_{OUT}/L_{DRC} time constant there is an error

DCR \rightarrow DC level still correct, the AC amplitude is attenuated

pliffe The LM25141-Q1 has a high-gain transconductance amplifier which generates an error current proportional to the difference between the feedback voltage and an internal precision reference (1.2 V). The output of the transconductance amplifier is connected to the COMP pin allowing the user to provide external control loop compensation. Generally for current mode control a type II network is recommended.

7.3.12 Slope Compensation

The LM25141-Q1 provides internal slope compensation to ensure stable operation with a duty cycle greater than 50%. To correctly use the internal slope compensation, the inductor value must be calculated based on the following guidelines [\(Equation](#page-19-1) 13 assumes an inductor ripple current of 30%):

$$
L_{OUT} \ge \frac{V_{OUT}}{Fsw \times (0.3 \times I_{OUT})}
$$
\n(13)

- Lower inductor values increase the peak-to-peak inductor current, which minimizes size and cost and improves transient response at the cost of reduced efficiency due to higher peak currents.
- Higher inductance values decrease the peak-to-peak inductor current typically increases efficiency by reducing the RMS current at the cost of requiring larger output capacitors to meet load-transient specifications.

7.3.13 Hiccup Mode Current Limiting

The LM25141-Q1 includes an optional hiccup mode protection function that is enabled when a capacitor is connected to the RES pin. In normal operation the RES capacitor is discharged to ground. If 512 consecutive cycles of cycle-by-cycle current limiting occur, the SS pin capacitor is pulled low and the HO and LO outputs are disabled (refer to *[Figure](#page-20-0) 26*). A 20-μA current source begins to charge the RES capacitor.

When the RES pin charges to 1.2 V, the RES pin is pulled low and the SS capacitor begins to charge. The 512 cycle hiccup counter is reset if 4 consecutive switching cycles occur without exceeding the current limit threshold. The controller is in forced PWM (FPWM) continuous conduction mode when the DEMB pin is connected to VDDA. In this mode the SS pin is clamped to a level 200 mV above the feedback voltage to the internal error amplifier. This ensures that SS can be pulled low quickly during a brief overcurrent event and prevent overshoot of VOUT when the overcurrent condition is removed.

If DEMB=0 V, the controller operates in diode emulation with light loads (discontinuous conduction mode) and the SS pin is allowed to charge to VDDA. This reduces the quiescent current of the LM25141-Q1. If 32 or more cycle-by-cycle current limit events occur, the SS pin is clamped to 200 mV above the feedback voltage to the internal error amplifier until the hiccup counter is reset. Thus, if a momentary overload occurs that causes at least 32 cycles of current limiting, the SS capacitor voltage is slightly higher than the FB voltage and controls VOUT during overload recovery.

Figure 26. Hiccup Mode

7.3.14 Standby Mode

The LM25141-Q1 operates with peak current mode control such that the compensation voltage is proportional to the peak inductor current. During no-load or light load conditions, the output capacitor will discharge very slowly. As a result, the compensation voltage does not demand a driver output pulses on a cycle-by-cycle basis. When the LM25141-Q1 controller detects that there have been 16 missing switching cycles, it enters Standby Mode and switches to a low IQ state to reduce the current drawn from VIN. For the LM25141-Q1 to go into a Standby Mode, the controller must be programmed for diode emulation (DEMB pin $<$ 0.4 V). The typical IQ in Standby Mode is 35 μA with VOUT regulating at 3.3 V.

7.3.15 Soft Start

The soft-start feature allows the controller to gradually reach the steady-state operating point, thus reducing startup stresses and surges. The LM25141-Q1 regulates the FB pin to the SS pin voltage or the internal 1.2-V reference, whichever is lower. At the beginning of the soft-start sequence when SS = 0 V, the internal 20-µA softstart current source gradually increases the voltage on an external soft-start capacitor connected to the SS pin, resulting in a gradual rise of the FB and output voltages. The controller is in the forced PWM (FPWM) mode when the DEMB pin is connected to VDDA. In this mode, the SS pin is clamped at 200 mV above the feedback voltage. This ensures that SS will be pulled low quickly when FB falls during brief overcurrent events to prevent overshoot of VOUT during recovery. SS can be pulled low with an external circuit to stop switching, but TI does not recommends this. Pulling SS low results in COMP being pulled down internally, as well. If the controller is operating in FPWM mode (DEMB = VDDA), LO remains on and the low-side MOSFET discharges the VOUT capacitor resulting in large negative inductor current. In contrast when the LM25141-Q1 pulls SS low internally due to a fault condition, the LO gate driver is disabled.

7.3.16 Diode Emulation

A fully synchronous buck controller implemented with a free-wheel MOSFET rather than a diode has the capability to sink negative current from the output in certain conditions such as light load, overvoltage, and prebias start-up. The LM25141-Q1 provides a diode emulation feature that can be enabled to prevent reverse (drain to source) current flow in the low-side free-wheel MOSFET. The diode emulation feature is configured with the DEMB pin. To enable diode emulation, connect the DEMB pin to ground. When configured for diode emulation, the low-side MOSFET is disabled when reverse current flow is detected. The benefit of this configuration is lower power loss at no load or light load conditions and the ability to turn on into a prebiased output without discharging the output. The negative effect of diode emulation is degraded light load transient response times. Enabling the diode emulation feature is recommended to allow discontinuous conduction operation. If continuous conduction operation is desired, the DEMB pin must be tied to VDDA.

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NSTRUMENTS

Table 2. DEMB Pin Modes

7.3.17 High- and Low-Side Drivers

The LM25141-Q1 contains N-channel MOSFET gate drivers and an associated high-side level shifter to drive the external N-channel MOSFETs. The high-side gate driver works in conjunction with an external bootstrap diode D_{BST} , and bootstrap capacitor C_{BST} (refer to [Figure](#page-21-0) 27). During the on-time of the low-side MOSFET, the SW pin voltage is approximately 0 V and C_{BST} is charged from VCC through the D_{BST}. A 0.1-µF or larger ceramic capacitor, connected with short traces between the HB and SW pin is recommended.

The LO and HO outputs are controlled with an adaptive dead-time methodology which ensures that both outputs (HO and LO) are never enabled at the same time, preventing cross conduction. When the controller commands LO to be enabled, the adaptive dead-time logic first disables HO and waits for the HO-SW voltage to drop below 2.5 V typical. LO is then enabled after a small delay (HO falling to LO rising delay). Similarly, the HO turnon is delayed until the LO voltage has dropped below 2.5 V. HO is then enabled after a small delay (LO falling to HO rising delay). This technique ensures adequate dead-time for any size N-channel MOSFET device or parallel MOSFET configurations. Caution is advised when adding series gate resistors, as this may decrease the effective dead-time. Each of the high and low-side drivers have independent driver source and sink output pins. This allows the user to adjust drive strength to optimize the switching losses for maximum efficiency and to control the slew rate for reduced EMI. The selected N-channel high-side MOSFET determines the appropriate boost capacitance values C_{BST} in the Figure 27 according to [Equation](#page-21-1) 14.

$$
C_{\text{BST}} = \frac{Q_{\text{G}}}{\Delta V_{\text{BST}}}
$$

where

- Q_G is the total gate charge of the high-side MOSFET
- $\Delta V_{\rm BST}$ is the voltage variation allowed on the high-side MOSFET driver after turnon (14)

Choose $\Delta V_{\rm BST}$ such that the available gate-drive voltage is not significantly degraded when determining C_{BST}. A typical range of $\Delta V_{\rm BST}$ is 100 mV to 300 mV. The bootstrap capacitor should be a low-ESR ceramic capacitor. A minimum value of 0.1 μ F to 0.47 μ F is best in most cases. The gate threshold of the high-side and low-side MOSFETs should be a logic level variety appropriate for 5-V gate drive.

Figure 27. Drivers

8 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

The LM25141-Q1 is a synchronous buck controller used to convert a higher input voltage to a lower output voltage. The following design procedure can be used to select external component values. Alternately, the WEBENCH[®]software may be used to generate a complete design. The WEBENCH software uses an iterative design procedure and accesses a comprehensive database of components when generating a design. This section presents a simplified design process. In addition to the WEBENCH software, the user should avail of the LM25141-Q1 [quick-start](http://www.ti.com/lit/pdf/http://www.ti.com/product/LM25141-Q1/toolssoftware#softTools) calculator.

For step-by-step design procedure, circuit schematics, bill of materials, PCB files, simulation and test results of an LM25141-Q1-powered implementation, see *TI [Designs](http://www.ti.com/tidesigns)* reference design library.

V_{IN} C_{IN} VIN **VCC** vcc D_{BST} HB C_{BST} RES HO L_{OUT} R_{SENSE} SS V_{OUT} HOL SW DITH LM25141-Q1 LO C_{RES} C_{SS} C_{DIT} LOL PGND PG EN CS DEMB VOUT **VCCX** R_{COMP} C_{COMP} **COMP** w~ FB AGND RT OSC VDDA R_{T} \leftarrow $\frac{1}{\sqrt{2}}$ C_{VDDA} Copyright © 2016, Texas Instruments Incorporated

8.2 Typical Application

Figure 28. Typical Application Schematic

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COUT

Typical Application (continued)

8.2.1 Design Requirements

For this design example, the intended input, output, and performance parameters are shown in [Table](#page-23-0) 3.

Table 3. Design Requirements

8.2.2 Detailed Design Procedure

- Buck Inductor value
- Calculate the peak inductor current
- Current Sense resistor value
- Output capacitor value
- Input filter
- MOSFET selection
- Control Loop design

8.2.2.1 Custom Design With WEBENCH® Tools

[Click](https://webench.ti.com/wb5/WBTablet/PartDesigner/quickview.jsp?base_pn=LM25141-Q1&origin=ODS&litsection=application) here to create a custom design using the LM25141-Q1 device with the WEBENCH® Power Designer.

- 1. Start by entering the input voltage (V_{IN}) , output voltage (V_{OUT}) , and output current (I_{OUT}) requirements.
- 2. Optimize the design for key parameters such as efficiency, footprint, and cost using the optimizer dial.
- 3. Compare the generated design with other possible solutions from Texas Instruments.

The WEBENCH Power Designer provides a customized schematic along with a list of materials with real-time pricing and component availability.

In most cases, these actions are available:

- Run electrical simulations to see important waveforms and circuit performance
- Run thermal simulations to understand board thermal performance
- Export customized schematic and layout into popular CAD formats
- Print PDF reports for the design, and share the design with colleagues

Get more information about WEBENCH tools at [www.ti.com/WEBENCH.](http://www.ti.com/lsds/ti/analog/webench/overview.page?DCMP=sva_web_webdesigncntr_en&HQS=sva-web-webdesigncntr-vanity-lp-en)

8.2.2.2 Inductor Calculation

For peak current mode control, sub-harmonic oscillation occurs with a duty cycle greater than 50% and is characterized by alternating wide and narrow pulses at the SW pin. By adding a slope compensating ramp equal to at least one-half the inductor current down-slope, any tendency toward sub-harmonic oscillation is damped within one switching cycle. For design simplification, the LM25141-Q1 has an internal slope compensation ramp added to the current sense signal.

For the slope compensation ramp to dampen sub-harmonic oscillation, the inductor value should be calculated based on the following guidelines [\(Equation](#page-23-1) 15 assumes an inductor ripple current 30%):

$$
L_{OUT} \geq \frac{V_{OUT}}{Fsw \times (0.3 \times I_{OUT})}
$$

- Lower inductor values increase the peak-to-peak inductor current, which minimizes size and cost and improves transient response at the expense of reduced efficiency due to higher peak currents.
- Higher inductance values decrease the peak-to-peak inductor current, which typically increases efficiency by reducing the RMS current but requires larger output capacitors to meet load-transient specifications.

$$
L_{OUT} \ge \frac{3.3 \text{ V}}{2.2 \text{ MHz} \times (0.3 \times 6 \text{ A})}
$$
\n
$$
L_{OUT} \ge 0.833 \mu \text{H}
$$
\n(16)

A standard inductor value of 1.5 µH was selected

$$
D_{MAX} = \frac{V_{OUT}}{V_{IN(MIN)}} = \frac{3.3 \text{ V}}{8 \text{ V}} = 0.413
$$
\n(17)

$$
D_{\text{MIN}} = \frac{V_{\text{OUT}}}{V_{\text{IN(MAX)}}} = \frac{3.3 \text{ V}}{18 \text{ V}} = 0.183 \tag{18}
$$

The peak-to-peak inductor current is:

$$
\Delta I = \frac{V_{IN(MAX)} - V_{OUT}}{L_{OUT}} \times \frac{D_{MIN}}{Fsw}
$$
 (19)

$$
\Delta I = \frac{18V - 3.3V}{1.5 \mu H} \times \frac{0.183}{2.2 MHz} = 0.815 A
$$
 (20)

$$
lpk = l_{OUT} + \frac{\Delta l}{2} \tag{21}
$$

$$
1pk = 6A + \frac{0.815}{2} = 6.41A
$$
\n(21)

8.2.2.3 Current Sense Resistor

When calculating the current sense resistor, the maximum output current capability ($I_{\text{OUT}(MAX)}$) should be at least 20% higher than the required full load current to account for tolerances, ripple current, and load transients. For this example, 120% of the 6.41-A peak inductor current calculated in the previous section (Ipk) is 7.69 A. The current sense resistor value can be calculated using [Equation](#page-24-0) 23:

$$
R_{\text{SENSE}} = \frac{V_{\text{(CS)}}}{I_{\text{OUT}(MAX)}}
$$

$$
R_{\text{SENSE}} = \frac{75 \text{ mV}}{7.69 \text{ A}} = 0.00975 \Omega
$$
 (23)

where

• $V_{(CS)}$ is the 75 mV current limit threshold (24)

The R_{SENSE} value selected is 9 m Ω

SENSE = $\frac{V_{\text{(CS)}}}{7.69 \text{ A}}$ = (

there

• $V_{\text{(CS)}}$ is the 75

ENSE value selecte

Ily observe the PC

Sense signals bet

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urrent to increase

eak current through
 $\frac{V_{\text{(CS)}}}{V_{$ Carefully observe the PCB layout guidelines to ensure that noise and DC errors do not corrupt the differential current sense signals between the CS and VOUT pins. Place the sense resistor close to the devices with short, direct traces, creating Kelvin-sense connections between the current-sense resistor and the LM25141-Q1.

The propagation delays through the current limit comparator, logic, and external MOSFET gate drivers allow the peak current to increase above the calculated current limit threshold. For a propagation delay of t_{div} , the worst case peak current through the inductor with the output shorted can be calculated from [Equation](#page-24-1) 25:

$$
Ipk_{SCKT} = \frac{V_{(CS)}}{R_{SENSE}} + \frac{V_{IN(MAX)} \times t_{dly}}{L_{OUT}}
$$

From the *Electrical [Characteristics](#page-5-2)*, t_{dly} is typically 40 ns.

25

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$$
1pk_{SCKT} = \frac{75mV}{0.009\Omega} + \frac{18V \times 40ns}{1.5\mu H} = 8.81A
$$

Once the peak current and the inductance parameters are known, the inductor can be chosen. An inductor with a saturation current greater than lpk_{SCKT} (8.81 Apk) should be selected.

8.2.2.4 Output Capacitor

SCKT = $\frac{1}{0.009\Omega}$ + $\frac{1.5\mu H}{1.5\mu}$

e peak current and the induc

on current greater than lpk_{SCK}
 Output Capacitor

tch mode power supply, the

urrent rating and the load tra

ctor energy and limit over v

un In a switch mode power supply, the minimum output capacitance is typically selected based on the capacitor ripple current rating and the load transient requirements. The output capacitor must be large enough to absorb the inductor energy and limit over voltage when transitioning from full-load to no-load, and to limit the output voltage undershoot during no-load to full load transients. The worst-case load transient from zero to full load occurs when the input voltage is at the maximum value and a current switching cycle has just finished. The total output voltage drop ΔV_{OUT} is the sum of the voltage drop while the inductor is ramping up to support the full load and the voltage drop before the next pulse can occur.

The output capacitance required to maintain the minimum output voltage drop (ΔV_{OUT}) can be calculated as follows:

$$
C_{OUT(MIN)} = \frac{L_{OUT} \times I_{STEP}^{2}}{2 \times \Delta V_{OUT} \times D_{MAX} \times (V_{IN(MIN)} - V_{OUT})}
$$

\n
$$
C_{OUT(MIN)} = \frac{1.5 \mu H \times 4 A^{2}}{2 \times 33 m V \times 0.413 \times (8 V - 3.3 V)} = 186 \mu F
$$
 (27)

where

•
$$
I_{\text{STEP}} = 4 \text{ A}
$$

• $\Delta V_{\text{OUT}} = 1\% \text{ of } 3.3 \text{ V, or } 33 \text{ mV}$ (28)

For this example a total of 211 μF of capacitance is used, two 82-μF aluminum capacitors for energy storage and one 47-μF low ESR ceramic capacitor to reduce high-frequency noise.

Generally, when sufficient capacitance is used to satisfy the undershoot requirement, the overshoot during a fullload to no-load transient is also satisfactory. After the output capacitance has been selected, calculate the output ripple current and verify that the ripple current is within the capacitor ripple current ratings.

$$
I_{OUT(RMS)} = \frac{\Delta I}{\sqrt{12}}
$$
(29)

$$
I_{OUT(RMS)} = \frac{0.815A}{\sqrt{12}} = 0.235A
$$
(30)

8.2.2.5 Input Filter

A power supply input typically has a relatively high source impedance at the switching frequency. Good-quality input capacitors are necessary to limit the ripple voltage at the VIN pin while supplying most of the switch current during the buck switch on-time. When the buck switch turns on, the current drawn from the input capacitor steps from zero to the valley of the inductor current waveform, then ramps up to the peak value, and then drops to the zero at turnoff.

Average input current can be calculated from the total input power required to support the load at V_{OUT} :

The efficiency (η) is assumed to be 83% for this design example, yielding a total input power:

$$
P_{IN} = \frac{3.3 \text{ V} \times 6 \text{ A}}{0.83} = 23.86 \text{ W}
$$
\n
$$
I_{avg} = \frac{P_{IN}}{V_{IN(MIN)}}
$$
\n(32)

(26)

$$
I_{avg} = \frac{28.6 \text{ W}}{8 \text{ V}} = 3.58 \text{ A}
$$
 (34)

The input capacitors should be selected with sufficient RMS current rating and the maximum voltage rating.

$$
I_{\text{avg}} = \frac{Q}{8V} = 3.36 \text{ A}
$$
\n(34)

\ninput capacitors should be selected with sufficient RMS current rating and the maximum voltage rating.

\n
$$
I_{\text{IN(RMS)}} = \sqrt{\left[\left(Ipk - I_{\text{avg}} \right)^2 + \frac{\Delta I^2}{12} \right] } \times D_{\text{MAX}} + \left(I_{\text{avg}}^2 \times (1 - D_{\text{MAX}}) \right)
$$
\n(35)

\n
$$
I_{\text{IN(RMS)}} = \sqrt{\left(6.41 \text{ A} - 3.58 \text{ A} \right)^2 + \frac{0.815^2}{1.2} \times 0.413 + \left(3.58 \text{ A}^2 \times (1 - 0.413) \right)} = 2.93 \text{ A}
$$

$$
I_{IN(RMS)} = \sqrt{(6.41A - 3.58A)^2 + \frac{0.815^2}{12} \times 0.413 + (3.58A^2 \times (1 - 0.413))} = 2.93A
$$
\n(36)

8.2.2.5.1 EMI Filter Design

EMI Filter Design Steps:

- Calculate the required attenuation
- Capacitor C_{IN} represents the existing capacitor at the input of the switching converter (10 μ F was used for this application)
- Inductor L_F is usually selected between 1 μ H and 10 μ H (1.8 μ H was used for this application), but can be smaller to reduce losses in a high current design
- Calculate capacitor C_F

Figure 29. Input EMI Filter

By calculating the first harmonic current from the Fourier series of the input current waveform and multiplying it by the input impedance (the impedance is defined by the existing input capacitor C_{IN}), a formula can be derived to obtain the required attenuation:

$$
|\text{Attn}| = 20 \times \log \left[\frac{\frac{\text{lpk}}{\pi^2 \times F_{SW} \times C_{IN}} \times \sin(\pi \times D_{MAX})}{1 \mu V} \right] - V_{MAX}
$$
\n
$$
|\text{Attn}| = 20 \log \left[\frac{\frac{6.41 \text{A}}{\pi^2 \times 2.2 \text{MHz} \times 10 \mu F} \times \sin(\pi \times 0.413)}{1 \mu V} \right] - 45 \text{ dB}_{\mu} = 44.07 \text{ dB}
$$
\n(38)

V_{MAX} is the allowed dB_HV noise level for the particular EMI standard. C_{IN} is the existing input capacitors of the Buck converter, for this application 10 μ F was selected. D_{MAX} is the maximum duty cycle, lpk is the inductor current, the current at the input can be modeled as a square wave, F_{SW} is the switching frequency.

$$
C_{F} = \frac{1}{L_{F}} \left[\frac{\frac{|Attn|}{10^{-40}}}{2 \times \pi \times F_{SW}} \right]^{2}
$$
\n
$$
C_{F} = \frac{1}{1.8 \,\mu\text{H}} \left(\frac{10^{\frac{44.07}{40}}}{2 \times \pi \times 2.2 \,\text{MHz}} \right)^{2} = 0.47 \,\mu\text{F}
$$
\n(40)

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For this application, C_F was chosen to be 1 μ F. Adding an input filter to a switching regulator modifies the controlto output transfer function. The output impedance of the filter must be sufficiently small such that the input filter does not significantly affect the loop gain of the buck converter. The impedance of the filter peaks at the filter resonant frequency.

$$
F_R = \frac{1}{2 \times \pi \sqrt{L_F C_{IN}}}
$$
\n
$$
F_R = \frac{1}{2 \times \pi \sqrt{1.8 \mu H \times 10 \mu F}} = 37.53 \text{kHz}
$$
\n(41)

Referring to [Figure](#page-26-0) 29, the purpose of R_D is to reduce the peak output impedance of the filter at the cutoff frequency. The capacitor C_D blocks the DC component of the input voltage, and avoids excessive power dissipation on R_D . The capacitor C_D should have lower impedance than R_D at the resonant frequency, with a capacitance value greater than 5 times the filter capacitor C_{IN} . This will prevent it from interfering with the cutoff frequency of the main filter. Added damping is needed when the output impedance is high at the resonant frequency (Q) of filter formed by C_{IN} and L_F is too high):

An electrolytic cap C_D can be used as damping device, with value:

$$
R_{D} = \sqrt{\frac{L_{F}}{C_{IN}}} \tag{43}
$$

For this design $C_D = 47 \mu F$ was selected

$$
R_{D} = \sqrt{\frac{1.8 \,\mu H}{10 \,\mu F}} = 0.424 \,\Omega \tag{44}
$$

8.2.2.5.2 MOSFET Selection

The LM25141-Q1 gate drivers are powered by the internal 5-V VCC bias regulator. To reduce power dissipation in the controller and improve efficiency, the VCCX pin should be connected to the 5-V output or an external 5-V bias supply. The MOSFETs used with the LM25141-Q1 require a logic-level gate threshold with $R_{DS(ON)}$ specified with V_{GS} = 4.5 V or lower.

2 MOSFET Selection
 10^{-1} $\sqrt{10 \mu F}$ = 0.42432
 2 MOSFET Selection
 125141 -Q1 gate drivers are powered by the internal 5-V

controller and improve efficiency, the VCCX pin should b

upply. The MOSFETs used with t The MOSFETs must be chosen with a V_{DS} rating to withstand the maximum V_{IN} voltage plus supply voltage transients and spikes (ringing). For automotive applications, the maximum V_{IN} occurs during a load dump and the voltage can surge up to 42 V under some conditions. A MOSFET with a V_{DS} rating of 60 V would meet most application requirements. The N-channel MOSFETs must be capable of delivering the load current plus peak ripple current during switching.

The high-side MOSFET losses are associated with the $R_{DS(ON)}$ of the MOSFET and the switching losses.

$$
P_{D(HS)} = (I_{OUT}^2 \times R_{DS(ON)} \times D_{MAX}) + \frac{1}{2} \times V_{IN} \times (t_r + t_f) \times I_{OUT} \times F_{SW}
$$

\n
$$
P_{D(HS)} = ((6A)^2 \times 0.026 \Omega \times 0.413) + \frac{1}{2} \times 12 \text{ V} \times (17 \text{ ns} + 17 \text{ ns}) \times 6 \text{ A} \times 2.2 \text{ MHz} = 2.69 \text{ W}
$$
\n(45)

where

•
$$
tr = ts = 17
$$
 ns (46)

The losses in the low side MOSFET include: $R_{DS(ON)}$ losses, dead time losses, and losses in the MOSFETs internal body diode. The body diode conducts the inductor current during the dead time before the rising edge of the switch node; minority carriers are injected into and stored in the diode PN junction when forward biased. As the high-side FET starts to turnon, a negative current must first flow through the diode to remove the stored charge before the diode can block a reverse voltage. During this time, the high side drain-source voltage remains at V_{IN} until all the diode minority carriers are removed. Then, the diode begins to block negative voltage and the reverse current continues to flow to charge the body diode depletion capacitance. The total charge involved in this period is called reverse-recovery charge Qrr.

$$
P_{D(LO)} = (I_{OUT}^2 \times R_{DS(ON)} \times (1 - D_{MAX})) + (I_{OUT} \times (t_{dr} + t_{df})) \times F_{SW} \times V_{D(FET)} + (D_{Qrr} \times F_{SW} \times V_{IN})
$$
\n(47)

 $P_{D(1,0)} = ((6A)^2 \times 26 \text{m}\Omega \times (1-0.413)) + (6A \times (20 \text{ns} + 20 \text{ns})) \times 2.2 \text{MHz} \times 0.8 \text{V} + (105 \text{nC} \times 2.2 \text{MHz} \times 12 \text{V}) = 3.744 \text{W}$

where

- t_{dr} and t_{dr} are the switch node voltage rise and fall times (20 ns)
- $V_{D(FET)}$ is the forward voltage drop across the low-side MOSFET internal body diode (0.8 V)
- D_{Qrr} is the internal body diode reverse recovery charge (105 nC)
- $R_{DS(ON)}$ is the on resistance of the MOSFETs (26 mΩ at T_J = 125°C) (48)

[Table](#page-28-1) 4 provides parameters for several MOSFETs that have tested in the LM25141-Q1 evaluation module.

Table 4. EVM MOSFETs

8.2.2.5.3 Driver Slew Rate Control

[Figure](#page-28-2) 30 shows the high current driver outputs with independent source and current sink pins for slew rate control. Slew rate control enables the user to adjust the switch node rise and fall times which can reduce the conducted EMI in the FM radio band (30 MHz to 108 MHz). Using the LM25141-Q1 EVM, conducted emissions were measured in accordance with CISPR 25 Class 5. [Figure](#page-29-0) 31 shows the measured results without slew rate control.

The conducted EMI results with slew rate control are shown in [Figure](#page-29-1) 32, a 10-dB reduction in conduction emissions in the FM band is attained by using slew rate control. This can help reduce the size and cost of the EMI filters.

Figure 30. Drivers With Slew Rate Control

Figure 31. EMI Measurements CISPR 25 Class 5, Without Slew Rate Control

Figure 32. EMI Measurements CISPR 25 Class 5, With Slew Rate Control

For technical solutions, industry trends, and insights for designing and managing power supplies, please refer to TI's *Power [House](http://e2e.ti.com/blogs_/b/powerhouse)* blog series.

8.2.2.5.4 Frequency Dithering

[Figure](#page-30-0) 33 shows the CISPR 25 Class 5 conducted emission test run on the LM25141-Q1EVM, without the Dither feature enabled. The first harmonic (peak measurement) is 48 dBµV, [Figure](#page-30-1) 34 shows the conducted emissions test results with the Dither feature enabled. With the Dither featured enabled, the first harmonic (peak measurement) was lowered to 40 dBµV, an 8-dB reduction.

Figure 33. CISPR 25 Class 5 Conducted EMI, Without Dither

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8.2.2.6 Control Loop

The open-loop gain is defined as the product of modulator transfer function and feedback transfer function. When plotted on a dB scale, the open-loop gain is shown as the sum of modulator gain and feedback gain.

DC modulator gain is:

$$
AM = \frac{R_{LOAD}}{(R_{SENSE} + R_{DCR}) \times G_{CS}}
$$
(49)

The modulator gain plus power stage transfer function with an embedded current loop is show in [Equation](#page-31-0) 50. The [Equation](#page-31-0) 50 includes the sample gain at F_{SW} /2 (ω_n) , which is caused by sampling effect of current mode control.

$$
\frac{\hat{V}_{OUT}}{\hat{V}_{C}(s)} = AM \times \frac{\left(1 + \frac{s}{\omega_{Z}}\right)}{\left(1 + \frac{s}{\omega_{P}}\right) \times \left(1 + \frac{s}{\omega_{n}Q} + \frac{s^{2}}{\omega_{n}^{2}}\right)}
$$

where

•
$$
s = 2 \times \pi \times F_{SW}
$$

\n
$$
Q = \frac{1}{\pi (K - 0.5)}
$$
\n• $\omega_Z = \frac{1}{C_{ESR} \times C_{OUT}}$
\n• $\omega_p = \frac{1}{R_{LOAD} \times C_{OUT}}$
\n• $\omega_n = \pi \times F_{SW}$
\n• $K = 1$

• G_{CS} is the current sense amplifier gain which is 12 (50)

Because the loop cross over frequency is well below sample gain effects, [Equation](#page-31-0) 50 can be simplified as one pole and a one zero system as shown in [Equation](#page-31-1) 51.

$$
\frac{\hat{V}_{OUT}(s)}{\hat{V}_{C}(s)} = AM \times \frac{\left(1 + \frac{s}{\omega_{Z}}\right)}{\left(1 + \frac{s}{\omega_{p}}\right)}
$$
\n(51)

 R_{LOAD} is the load resistance

 R_{DCR} is the DC resistance on the output inductor which is 8.1 m Ω

 R_{SENSE} is the current sense resistance which is 9 m Ω

8.2.2.6.1 Feedback Compensator

A type II compensator using an transconductance error amplifier (EA), Gm, is shown in [Figure](#page-32-1) 35. The dominant pole of the EA open-loop gain is set by the EA output resistance, R_{AMP}, and effective bandwidth-limiting capacitance, C_O , as follows:

$$
G_{EA(\text{openloop})}(s) = -\frac{GmR_{AMP}}{1 + sR_{AMP}C_{O}}
$$
(52)

The EA high frequency pole is neglected in the above expression. The compensator transfer function from output voltage to COMP, including the gain contribution from the feedback resistor divider network is:

$$
G_{C}(s) = \frac{\hat{V}_{C}(s)}{\hat{V}_{OUT}(s)} = -\frac{V_{REF}}{V_{OUT}} \times Gm \times Z_{EAOUT}(s)
$$
\n(53)

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(54)

 $\frac{LOWER}{E} = \frac{VREF}{E}$ $R_{\text{LOWER}} + R_{\text{UPPER}} - \sqrt{V_{\text{OUT}}}$ R_{LOWER}

where

$$
Z_{EAOUT}(s) = Gm \times \left(R_{AMP} \left\| \left(R_{COMP} + \frac{1}{sC_{COMP}} \right) \right\| \frac{1}{sC_{HF}} \left\| \frac{1}{sC_O} \right\}
$$

Which simplifies to:

$$
Z_{EAOUT}(s) = R_{AMP} \frac{1 + \frac{s}{\omega_{zEA}}}{\left(1 + \frac{s}{\omega_{pEA1}}\right) \times \left(1 + \frac{s}{\omega_{pEA2}}\right)}
$$
\n
$$
R_{UPPER} \leq \frac{Gm}{\sqrt{R_{UPPER}}} \tag{55}
$$

Figure 35. Transconductance Amplifier

$$
\omega_{zEA} = \frac{1}{R_{COMP} \times C_{COMP}}
$$
\n
$$
\omega_{pEA1} = \frac{1}{(R_{AMP} + R_{COMP})(C_{COMP} + C_{HF} + C_{O})} \approx \frac{1}{R_{AMP} \times C_{COMP}}
$$
\n(56)

$$
\omega_{\text{pEA1}} = \frac{1}{(R_{\text{AMP}} + R_{\text{COMP}})(C_{\text{COMP}} + C_{\text{HF}} + C_{\text{O}})} \approx \frac{1}{R_{\text{AMP}} \times C_{\text{COMP}}}
$$
(57)

$$
\omega_{\text{PEA2}} = \frac{1}{R_{\text{COMP}} \left(C_{\text{COMP}} \|(C_{\text{HF}} + C_{\text{O}})\right)} \approx \frac{1}{R_{\text{COMP}} \times C_{\text{HF}}} \tag{58}
$$
\n
$$
\text{ally } R_{\text{COMP}} \ll R_{\text{AMP}} \text{ and } C_{\text{COMP}} \gg (C_{\text{HF}} + C_{\text{O}}) \text{ so the approximations are valid.}
$$
\n
$$
\text{as the feedback voltage reference (1.2 V)}
$$
\n
$$
\text{the error amplifier gain transconductance (1200 }\mu\text{S})
$$
\n
$$
\text{is the error amplifier output impedance (2.5 MΩ)}
$$
\n
$$
\text{error amplifier compensation components create a pole at the origin, a zero, and a high frequency pole.}
$$
\n
$$
\text{procedure for choosing compensation components for a stable closed loop is:}
$$
\n
$$
\text{P_{\text{COMP}}} = \text{for the desired open-loop gain crossover frequency (fc); for this application 30 kHz was chosen}
$$
\n
$$
\text{allow the R}_{\text{COMP}} = \text{for } \frac{V_{\text{OUT}}}{V_{\text{V}}} \times \frac{2 \times \pi \times C_{\text{OUT}} \times (R_{\text{SENSE}} + R_{\text{DCR}}) \times G_{\text{CS}}}{R_{\text{COMP}}} \approx \frac{V_{\text{OUT}}}{V_{\text{V}}} \times \frac{2 \times \pi \times C_{\text{OUT}} \times (R_{\text{SENSE}} + R_{\text{DCR}}) \times G_{\text{CS}}}{R_{\text{OMP}}} \approx \frac{V_{\text{OUT}}}{V_{\text{V}}}
$$

Typically $R_{COMP} \ll R_{AMP}$ and $C_{COMP} \gg (C_{HF} + C_0)$ so the approximations are valid.

where

 V_{REF} is the feedback voltage reference (1.2 V)

 G_m is the error amplifier gain transconductance (1200 µS)

 R_{AMP} is the error amplifier output impedance (2.5 M Ω)

The error amplifier compensation components create a pole at the origin, a zero, and a high frequency pole.

The procedure for choosing compensation components for a stable closed loop is:

- Select the desired open-loop gain crossover frequency (fc); for this application 30 kHz was chosen
- Calculate the R_{COMP} resistor for the gain crossover frequency at 30 kHz

$$
R_{COMP} = fc \frac{V_{OUT}}{V_{REF}} \times \frac{2 \times \pi \times C_{OUT} \times (R_{SENSE} + R_{DCR}) \times G_{CS}}{Gm}
$$
\n
$$
R_{COMP} = 30KHz \times \frac{3.3V}{1.2V} \times \frac{2 \times \pi \times 293 \mu F \times (0.009 \Omega + 0.0081 \Omega) \times 12}{1200 \times 10^{-6} \mu S} = 25927 \Omega
$$
\n(60)

The value selected for R_{COMP} is 22.6 kΩ. where

 $R_{DCR} = 0.0081 \Omega$

• Calculate the C_{COMP} capacitor value to create a zero that cancels the pole ω_p (ω_p = 1/R_{LOAD} × C_{OUT})

$$
C_{COMP} = \frac{R_{LOAD} \times C_{OUT}}{R_{COMP}}
$$

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(62)

 $\text{C}_{\text{COMP}}=\frac{0.477 \Omega \times 290 \,\mu\text{F}}{22.6 \,\text{k}\Omega}=6 \,\text{nF}$ $=\frac{0.477\Omega\times290\,\mu}{22.6\,\text{k}\Omega}$

The value selected for C_{COMP} is 10 nF.

8.2.3 Application Curves

[LM25141-Q1](http://www.ti.com/product/lm25141-q1?qgpn=lm25141-q1)

The Bode Plots of the modulator and plus power stage are shown in refer to [Figure](#page-33-0) 36. The results of the total loop gain crossover frequency are 40 kHz with 112^o of phase margin, (see [Figure](#page-33-1) 37).

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9 Power Supply Recommendations

The LM25141-Q1EVM was designed to operate over an input voltage supply range between 5.5 V and 42 V. The input supply must be well regulated. If the power source is located more than a few inches from the LM25141-Q1 EVM, additional bulk capacitance and ceramic bypass capacitors may be required at the power supply input. An electrolytic capacitor with a value of 47μ F is typically a good choice.

10 Layout

10.1 Layout Guidelines

Careful PCB layout is critical to achieve low EMI and stable power supply operation. Make the high-frequency current loops as small as possible, and follow these guidelines of good layout practices:

- 1. Keep the high-current paths short. This is essential for stable, jitter-free operation.
- 2. Keep the power traces and load connections short. This is essential for high efficiency. Using 2-oz. or thicker copper can enhance full load efficiency.
- 3. Minimize current-sensing errors by routing CS and VOUT using a kelvin sensing directly across the current sense resistor (R_{SENSE}) .
- 4. Route high-speed switching nodes (HB, HO, LO, and SW) away from sensitive analog signals (FB, CS, and VOUT).

10.1.1 Layout Procedure

Place the power components first, with ground terminals adjacent to the low-side FET.

- Mount the controller IC as close as possible to the high and low-side MOSFETs. Make the grounds and high and low-sided drive gate drive lines as short and wide as possible. Place the series gate drive resistor as close to the MOSFET as possible to minimize gate ringing.
- Locate the gate drive components (D1 and C12) together and near the controller IC; refer to [Figure](#page-35-1) 38. Be aware that peak gate drive currents can be as high as 4 A. Average current up to 75 mA can flow from the VCC pin to the V_{CC} capacitor through the bootstrap diode to the bootstrap capacitor. Size the traces accordingly.
- [Figure](#page-35-2) 39 shows the high-frequency loops of the synchronous buck converter. The high frequency current flows through Q1 and Q2, through the power ground plane and back to V_{IN} through the ceramic capacitors C6, C7, and C8. This loop must be as small as possible to minimize EMI. Refer to [Figure](#page-36-0) 41 and [Figure](#page-37-0) 42 for the recommended PCB layout.
- Make the PGND and AGND connections to the LM25141-Q1 controller as shown in [Figure](#page-36-1) 40. Create a power grounds directly connected to all high-power components and an analog ground plane for sensitive analog components. The analog ground plane (AGND) and power ground plane (PGND) must be connected at a single point directly under the IC (at the die attach pad or DAP).

10.2 Layout Examples

Figure 38. EVM Top Side

Figure 39. EVM Bottom Layer, High-Frequency Current Loop

Layout Examples (continued)

Figure 40. AGND and PGND Connections

[Figure](#page-36-0) 41 and [Figure](#page-37-0) 42 show the Top and Bottom layer of the LM25141-Q1 EVM.

Figure 41. EVM Top Layer

Downloaded From [Oneyac.com](https://www.oneyac.com)

Layout Examples (continued)

Figure 42. EVM Bottom Layer

11 Device and Documentation Support

11.1 Device Support

11.1.1 Development Support

For development support see the following:

- LM25141-Q1 Design [Calculator](http://www.ti.com/product/LM25141-Q1/toolssoftware#softTools)
- LM25141-Q1 [Simulation](http://www.ti.com/product/LM25141-Q1/toolssoftware#simulationmodels) Models
- For TI's reference design library, visit TI [Designs](http://www.ti.com/tidesigns)
- For TI's [WEBENCH](http://www.ti.com/lsds/ti/analog/webench/overview.page) Design Environment, visit the WEBENCH® Design Center
- To view a related device of this product, see the [LM5140-Q1](http://www.ti.com/product/lm5140-q1) 65-V, low I_0 dual synchronous buck controller

11.1.1.1 Custom Design With WEBENCH® Tools

[Click](https://webench.ti.com/wb5/WBTablet/PartDesigner/quickview.jsp?base_pn=LM25141-Q1&origin=ODS&litsection=device_support) here to create a custom design using the LM25141-Q1 device with the WEBENCH® Power Designer.

- 1. Start by entering the input voltage (V_{IN}) , output voltage (V_{OUT}) , and output current (I_{OUT}) requirements.
- 2. Optimize the design for key parameters such as efficiency, footprint, and cost using the optimizer dial.
- 3. Compare the generated design with other possible solutions from Texas Instruments.

The WEBENCH Power Designer provides a customized schematic along with a list of materials with real-time pricing and component availability.

In most cases, these actions are available:

- Run electrical simulations to see important waveforms and circuit performance
- Run thermal simulations to understand board thermal performance
- Export customized schematic and layout into popular CAD formats
- Print PDF reports for the design, and share the design with colleagues

Get more information about WEBENCH tools at [www.ti.com/WEBENCH.](http://www.ti.com/lsds/ti/analog/webench/overview.page?DCMP=sva_web_webdesigncntr_en&HQS=sva-web-webdesigncntr-vanity-lp-en)

11.2 Documentation Support

11.2.1 Related Documentation

For related documentation see the following:

- *[LM5141QRG](http://www.ti.com/lit/pdf/SNVU522) Synchronous Buck Converter Evaluation Module*
- *Reduce Buck Converter EMI and Voltage Stress by [Minimizing](http://www.ti.com/lit/pdf/SLYT682) Inductive Parasitics*
- *Designing [High-performance,](http://www.ti.com/lit/pdf/SNVA780) Low-EMI Automotive Power Supplies*
- TI Reference Designs:
	- *Automotive [Synchronous](http://www.ti.com/tool/PMP30249) Buck Reference Design* (TIDUDL3)
	- *Automotive [Synchronous](http://www.ti.com/tool/PMP30339) Buck With 3.3V @ 12.0A Reference Design* (TIDUDL6)
	- *[Synchronous](http://www.ti.com/tool/PMP20682) Buck Converter for Automotive Cluster Reference Design* (TIDUE07)
- White Papers:
	- *Valuing Wide VIN, Low-EMI Synchronous Buck Circuits for [Cost-Effective,](http://www.ti.com/lit/pdf/SLYY104) Demanding Applications*
- Power House Blogs:
	- *How to use Slew Rate for EMI [Control](https://e2e.ti.com/blogs_/b/powerhouse/archive/2016/03/21/how-to-use-slew-rate-for-emi-control)*
	- *Exploiting [Current-mode](http://e2e.ti.com/blogs_/b/powerhouse/archive/2014/08/14/exploiting-current-mode-control-for-wide-vin-dc-dc-conversion) Control for Wide Vin DC/DC Conversion*
	- *[Synchronous](https://e2e.ti.com/blogs_/b/powerhouse/archive/2017/06/29/synchronous-buck-controller-solutions-support-wide-vin-performance-and-flexibility) Buck Controller Solutions Support Wide VIN Performance and Flexibility*

11.2.1.1 PCB Layout Resources

- *AN-1149 Layout [Guidelines](http://www.ti.com/lit/pdf/SNVA021) for Switching Power Supplies*
- *AN-1229 Simple Switcher PCB Layout [Guidelines](http://www.ti.com/lit/pdf/SNVA054)*
- *Constructing Your Power Supply – Layout [Considerations](http://www.ti.com/lit/pdf/SLUP230)*
- *[High-Density](https://e2e.ti.com/blogs_/b/powerhouse/archive/2015/09/16/high-density-pcb-layout-of-dc-dc-converters-part-2) PCB Layout of DC/DC Converters*

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Documentation Support (continued)

11.2.1.2 Thermal Design Resources

- *AN-2020 Thermal Design by Insight, Not [Hindsight](http://www.ti.com/lit/pdf/SNVA419)*
- *AN-1520 A Guide to Board Layout for Best Thermal [Resistance](http://www.ti.com/lit/pdf/SNVA183) for Exposed Pad Packages*
- *[Semiconductor](http://www.ti.com/lit/pdf/SPRA953) and IC Package Thermal Metrics*
- *Thermal Design Made Simple with [LM43603](http://www.ti.com/lit/pdf/SNVA719) and LM43602*
- *[PowerPAD™Thermally](http://www.ti.com/lit/pdf/SLMA002) Enhanced Package*
- *[PowerPAD](http://www.ti.com/lit/pdf/SLMA004) Made Easy*
- *Using New [Thermal](http://www.ti.com/lit/pdf/SBVA025) Metrics*

11.3 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

11.4 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms](http://www.ti.com/corp/docs/legal/termsofuse.shtml) of [Use.](http://www.ti.com/corp/docs/legal/termsofuse.shtml)

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Design [Support](http://support.ti.com/) *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

11.5 Trademarks

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11.6 Electrostatic Discharge Caution

This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

11.7 Glossary

[SLYZ022](http://www.ti.com/lit/pdf/SLYZ022) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the \leq =1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF LM25141-Q1 :

• Catalog : [LM25141](http://focus.ti.com/docs/prod/folders/print/lm25141.html)

NOTE: Qualified Version Definitions:

• Catalog - TI's standard catalog product

TEXAS

TAPE AND REEL INFORMATION

ISTRUMENTS

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

Pack Materials-Page 1

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PACKAGE MATERIALS INFORMATION

*All dimensions are nominal

Pack Materials-Page 2

GENERIC PACKAGE VIEW

RGE 24 VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD

Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

PACKAGE OUTLINE

RGE0024B VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD

NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

EXAMPLE BOARD LAYOUT

RGE0024B VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).

5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

EXAMPLE STENCIL DESIGN

RGE0024B VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

PACKAGE OUTLINE

RGE0024J VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD

NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

EXAMPLE BOARD LAYOUT

RGE0024J VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).

5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

EXAMPLE STENCIL DESIGN

RGE0024J VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

RGE0024N

PACKAGE OUTLINE

VQFN - 1 mm max height

PLASTIC QUAD FLATPACK-NO LEAD

NOTES:

- per ASME Y14.5M.
This drawing is subject to change without notice.
-
-

EXAMPLE BOARD LAYOUT

RGE0024N VQFN - 1 mm max height

PLASTIC QUAD FLATPACK-NO LEAD

NOTES: (continued)

-
- on this view. It is recommended that vias under paste be filled, plugged or tented.

EXAMPLE STENCIL DESIGN

RGE0024N VQFN - 1 mm max height

PLASTIC QUAD FLATPACK-NO LEAD

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

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